

MIC5319

500 mA, µCap Ultra-Low Dropout Regulator with High PSRR

Features

- Ultra-Low Dropout Voltage: 200 mV @ 500 mA
- Input Voltage Range: 2.5V to 5.5V
- Output Voltage:
- Adjustable: V_{REF} = 1.25V
- Fixed: 1.3V, 1.8V, 1.85V, 2.5V, 2.6V, 2.7V,
 2.8V, 2.85V, 2.9V, 3.0V, 3.3V
- · Stable with Low ESR Ceramic Output Capacitor
- Low Output Noise: 40 μV_{RMS} (10 Hz to 100 kHz Bandwidth)
- Low Ground Current: 90 µA Typical
- High PSRR, up to 70 dB @ 1 kHz
- Fast Turn-On Time: 40 µs Typical
- · High Output Accuracy:
 - ±1.0% Initial Accuracy
- ±2.0% Over Temperature
- Thermal-Shutdown Protection
- Current-Limit Protection
- · Logic-Controlled Enable Input Pin
- · Available Packages:
- 2 mm x 2 mm DFN, 500 mA Continuous
- SOT23-5, 500 mA Peak

Applications

- · Cellular Phones
- PDAs
- · Fiber Optic Modules
- · Portable Electronics
- Notebook PCs
- · Audio Codec Power Supplies

Package Types

MIC5319-x.xYML (FIXED) MIC5319-x.xYD5 MIC5319YML (ADJ.) 6-Lead DFN (ML) 6-Lead DFN (ML) SOT23-5 (D5) (Top View) (Top View) (Top View) EN GND VIN 6 BYP EN 6 BYP EN 2 EΡ EP NC GND ADJ GND 5 2 5 VOUT VIN VOUT 3 VIN 4 5 BYP VOUT

General Description

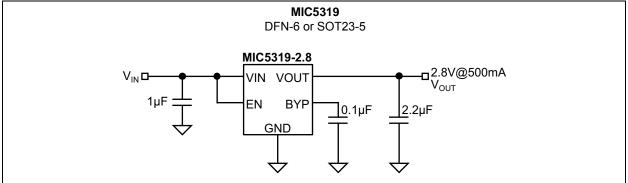
The MIC5319 is a high performance, 500 mA LDO regulator, with high PSRR and very low noise, with low ground current.

Ideal for battery-operated applications, the MIC5319 features 1% accuracy, very low dropout voltage (typically 200 mV @ 500 mA), and low ground current at light load (typically 90 μ A). Equipped with a logic-compatible enable pin, the MIC5319 can be set into a zero-off-mode current state, typically drawing only 0.5 μ A current when disabled.

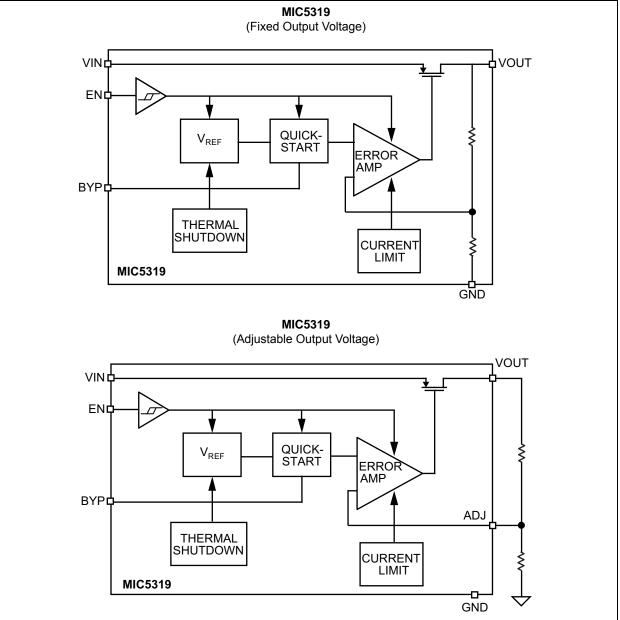
The MIC5319 is a μ Cap design operating with very small ceramic output capacitors for stability, thereby reducing required board space and component cost.

The MIC5319 is available in fixed-output voltages and adjustable output versions in the compact 2 mm x 2 mm DFN lead-less package or the thin SOT23-5 package.

Typical Application Circuit







1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Input Voltage (V _{IN})	0V to +6V
Enable Input Voltage (V _{EN})	
Power Dissipation (P _D) (Note 1)	Internally Limited
ESD Rating (Note 2)	

Operating Ratings ‡

Supply Input Voltage (V _{IN})	+2.5V to +5.5V
Enable Input Voltage (V _{EN})	0V to V _{IN}

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

‡ Notice: The device is not guaranteed to function outside its operating ratings.

- **Note 1:** The maximum allowable power dissipation of any T_A (ambient temperature) is $P_{D(MAX)} = (T_{J(MAX)} T_A)/\theta_{JA}$. Exceeding the maximum allowable power dissipation will result in excessive die temperature, and the regulator may go into thermal shutdown.
 - 2: Devices are ESD sensitive. Handling precautions recommended.

TABLE 1-1: ELECTRICAL CHARACTERISTICS

Electrical Characteristics: $V_{IN} = V_{OUT} + 1.0V$; $C_{OUT} = 2.2 \ \mu\text{F}$; $I_{OUT} = 100 \ \mu\text{A}$; $T_A = +25^{\circ}\text{C}$, **bold** values are available for the -40°C to $+125^{\circ}\text{C}$ junction temperature range, unless otherwise noted. (Note 1)

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
	-1.0 — 1.0			Variation from nominal V _{OUT}		
Output Voltage Accuracy	ΔV _{OUT}	-2.0		2.0	%	Variation from nominal V _{OUT} , I _{OUT} = 100 μ A to 500 mA
Feedback Voltage (Adj.	V	1.2375	1.25	1.2625	V	
Option)	V_{ADJ}	1.225	1.25	1.275	v	_
Line Regulation	ΔV _{OUT} /(V _{OUT} x ΔV _{IN})	_	0.04	0.3	%/V	$V_{IN} = V_{OUT} + 1V$ to +5.5V
Load Regulation (Note 2)	ΔV _{OUT} / V _{OUT}		0.1	0.5	%	I _L = 100 μA to 500 mA
Dropout Voltage (Note 3,			20	40	mV	I _{OUT} = 50 mA
Note 4)	V _{DO}		200	400	IIIV	I _{OUT} = 500 mA
Ground Pin Current (Note 5)	I _{GND}	_	90	150	μA	I _{OUT} = 0 mA to 500 mA
Ground Pin Current in Shutdown Mode	I _{SHDN}	_	0.5	-	μA	V _{EN} ≤ 0.2V
Power Supply Ripple		_	70	_	dB	f = up to 1 kHz; C _{OUT} = 2.2 μF ceramic; C _{BYP} = 0.1 μF
Rejection	PSRR	_	60	_	dB	f = 10 kHz; C _{OUT} = 2.2 μ F ceramic; C _{BYP} = 0.1 μ F
Current Limit	I _{LIMIT}	600	700	_	mA	V _{OUT} = 0V
Output Voltage Noise	e _N		40		μV _{RMS}	C _{OUT} = 2.2 μF; C _{BYP} = 0.1 μF; 10 Hz to 100 kHz
Turn-On Time	t _{ON}	_	40	100	μs	C _{OUT} = 2.2 μF; C _{BYP} = 0.1 μF
	V _{ENABLE}	_		0.2	V	Logic Low (Regulator Shutdown)
Enable Input Voltage		1.2		_	v	Logic High (Regulator Enabled)
Enable Input Current	1	_	0.01	1		V _{IL} = ≤ 0.2V (Regulator Shutdown)
Enable Input Current	I _{ENABLE}		0.01	1	μA	$V_{IH} = \ge 1.0V$ (Regulator Shutdown)

Note 1: Specification for packaged product only.

2: Regulation is measured at constant junction temperature using low duty cycle pulse testing.

3: Dropout voltage is defined as the input-to-output differential at which the output voltage drops 2% below its nominal V_{OUT} . For outputs below 2.5V, dropout voltage spec does not apply, as the part is limited by minimum V_{IN} spec of 2.5V. There may be some typical dropout degradation at V_{OUT} < 3V.

4: For Adjustable option, V_{OUT} = 3V for dropout specification.

5: Ground pin current is the regulator quiescent current. The total current drawn from the supply is the sum of the load current plus the ground pin current.

TEMPERATURE SPECIFICATIONS (Note 1)

	-					
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Junction Operating Temperature Range	Т _Ј	-40	—	+125	°C	_
Storage Temperature Range	Τ _S	-65	_	+150	°C	—
Lead Temperature	—	—	—	+260	°C	Soldering, 5s
Package Thermal Resistances						
Thermal Resistance DFN-6	θ_{JA}	_	93	_	°C/W	—
Thermal Resistance Thin SOT23-5	θ_{JA}	—	235	—	°C/W	—

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +125°C rating. Sustained junction temperatures above +125°C can impact the device reliability.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

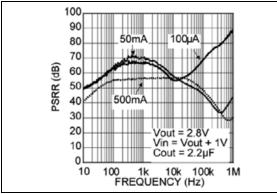


FIGURE 2-1: PSRR (Bypass Pin Capacitor = 0.1μ F).

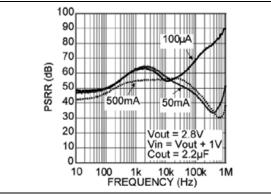


FIGURE 2-2: PSRR (Bypass Pin Capacitor = 0.01μ F).

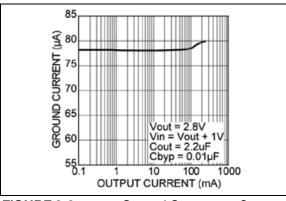


FIGURE 2-3: Ground Current vs. Output Current.

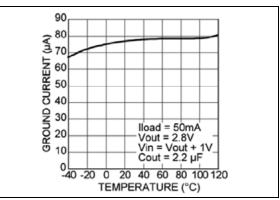
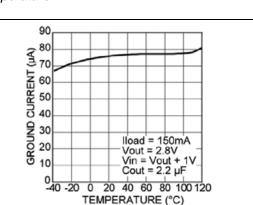


FIGURE 2-4: Temperature.



Ground Current vs.

FIGURE 2-5: Temperature.

Ground Current vs.

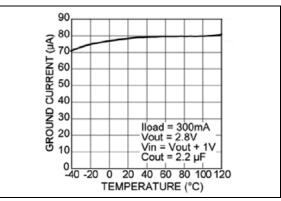
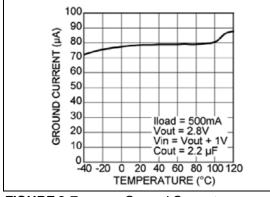


FIGURE 2-6: Temperature.

Ground Current vs.





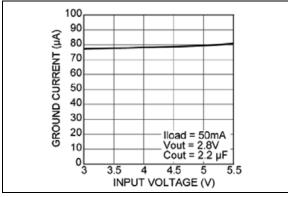


FIGURE 2-8: Ground Current vs. Input Voltage.

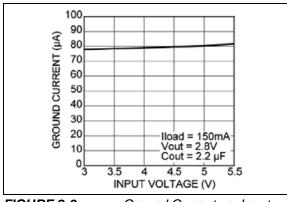


FIGURE 2-9: Voltage.

Ground Current vs. Input

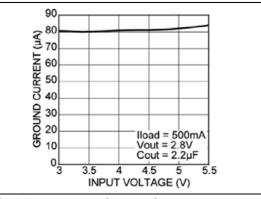


FIGURE 2-10: Ground Current vs. Input Voltage.

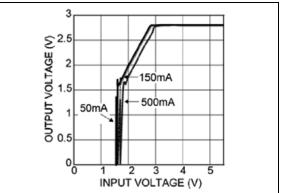


FIGURE 2-11:

Dropout Characteristics.

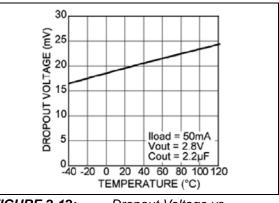


FIGURE 2-12:Dropout Voltage vs.Temperature.

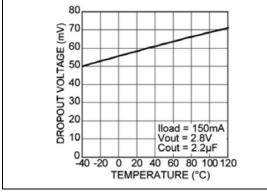


FIGURE 2-13:Dropout Voltage vs.Temperature.

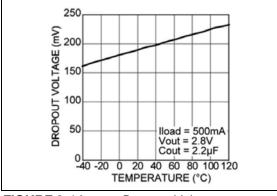


FIGURE 2-14: Dropout Voltage vs. Temperature.

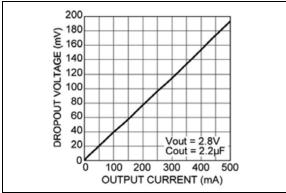


FIGURE 2-15: Dropout Voltage vs. Load Current.

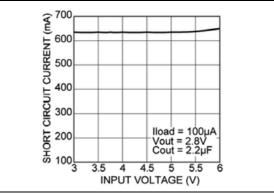


FIGURE 2-16: Short-Circuit Current vs. Input Voltage.

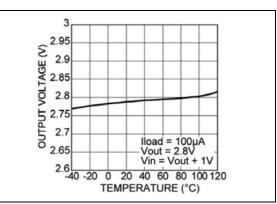


FIGURE 2-17: Output Voltage vs. Temperature.

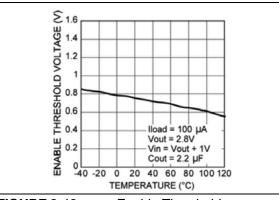
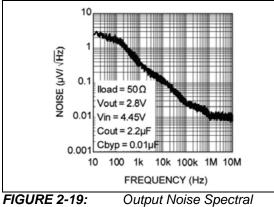


FIGURE 2-18:Enable Threshold vs.Temperature.



Density.

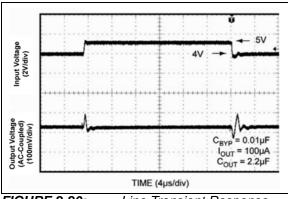
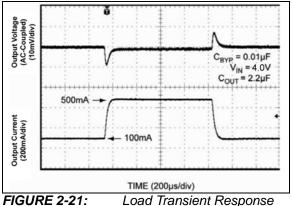


FIGURE 2-20: Line Transient Response (3.0V Fixed Output Version).



(3.0V Fixed Output Version).

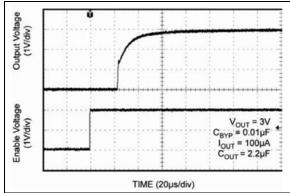
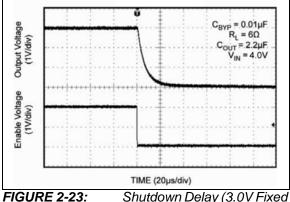


FIGURE 2-22: Enable Pin Delay (3.0V Fixed Output Version).



Output Version).

Shutdown Delay (3.0V Fixed

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1:	PIN FUNCTION TABLE
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Pin Number DFN-6, Fixed	Pin Number DFN-6, Adj.	Pin Number SOT23-5	Pin Name	Description
1	1	3	EN	Enable Input: Active-High. High = Regulator ON, Low = Regulator OFF. Do not leave floating.
2	2	2	GND	Ground.
3	3	1	VIN	Input Voltage.
4	4	5	VOUT	Output Voltage.
_	5	_	ADJ	Adjustable Input: Connect to the external resistor voltage divider network to set the desired output voltage.
5	_	_	NC	Not connected for the DFN fixed output voltage version.
6	6	4	BYP	Reference Bypass: Connect external 0.1 µF to GND for reduced output noise. May be left open.
EP	EP	—	EP	Exposed Pad connected to ground internally. Must be connected to the ground plane of the application board for optimal heat dissipation.

4.0 APPLICATION INFORMATION

4.1 Enable/Shutdown

The MIC5319 features an active-high enable pin that allows the regulator to be disabled. Forcing the enable pin low disables the regulator and sends it into a "zero" off-mode current state. In this state, the current consumed by the regulator is typically only 0.5 μ A. Forcing the enable pin high enables the output voltage. The active-high enable pin uses CMOS technology and the enable pin cannot be left floating, as this may cause an undetermined state on the output.

4.2 Input Capacitor

The MIC5319 is a high-performance, high bandwidth device. Therefore, it requires a well-bypassed input supply for optimal performance. A minimum 1 μ F capacitor is required from the input-to-ground to provide stability. Low-ESR ceramic capacitors provide optimal performance at a minimum of space. Additional high-frequency capacitors, such as small-valued NPO dielectric-type capacitors, help filter out high-frequency noise and are good design practice in any RF-based circuit.

4.3 Output Capacitor

The MIC5319 requires an output capacitor of 2.2 μ F or greater to maintain stability. The design is optimized for use with low-ESR ceramic chip capacitors. High ESR capacitors may cause high-frequency oscillation. The output capacitor can be increased, but performance has been optimized for a 2.2 μ F ceramic output capacitor and does not improve significantly with larger capacitance.

X7R/X5R dielectric-type ceramic capacitors are recommended because of their temperature performance. X7R-type capacitors change capacitance by 15% over their operating temperature range and are the most stable type of ceramic capacitors. Z5U and Y5V dielectric capacitors change value by as much as 50% and 60%, respectively, over their operating temperature ranges. To use a ceramic chip capacitor with Y5V dielectric, the value must be much higher than an X7R ceramic capacitor to ensure the same minimum capacitance over the equivalent operating temperature range.

4.4 Bypass Capacitor

A capacitor can be placed from the bypass pin-to-ground to reduce output voltage noise. The capacitor bypasses the internal reference. A $0.1 \,\mu\text{F}$ capacitor is recommended for applications that require low-noise outputs. The bypass capacitor can be increased, further reducing noise and improving PSRR. Turn-on time increases slightly with respect to bypass capacitance.

A unique, quick-start circuit allows the MIC5319 to drive a large capacitor on the bypass pin without significantly slowing turn-on time.

4.5 No-Load Stability

Unlike many other voltage regulators, the MIC5319 will remain stable and in regulation with no load. This is especially important in CMOS RAM keep-alive applications.

4.6 Adjustable Regulator Application

Adjustable regulators use a two-resistor divider to multiply the reference voltage and to produce the desired output voltage.

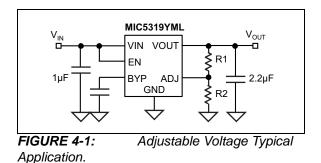
The MIC5319 output voltage can be adjusted from 1.25V to 5.5V by using two external resistors (Figure 4-1). The resistors set the output voltage based on the following equation:

EQUATION 4-1:

$$V_{OUT} = V_{REF} \left(1 + \frac{R1}{R2} \right)$$

Where:

V_{REF} = 1.25V



4.7 Thermal Considerations

The MIC5319 is designed to provide 500 mA of continuous current in a very small DFN package. Maximum ambient operating temperature can be calculated based on the output current and the voltage drop across the part. Given an input voltage of 3.3V, output voltage of 2.8V, and output current of 500 mA, the actual power dissipation of the regulator circuit can be determined using the equation:

EQUATION 4-2:

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} + V_{IN} \times I_{GND}$$

Because this device is CMOS and the ground current is typically <100 μ A over the load range, the power dissipation contributed by the ground current is <1% and can be ignored for this calculation:

EQUATION 4-3:

$$P_D = (3.3V - 2.8V) \times 500mA = 0.25W$$

To determine the maximum ambient operating temperature of the package, use the junction-to-ambient thermal resistance of the device and the following basic equation:

EQUATION 4-4:

$$P_{D(MAX)} = \frac{T_{J(MAX)} - T_A}{\theta_{JA}}$$

Where:

 $\begin{array}{ll} \mathsf{T}_{\mathsf{J}(\mathsf{MAX})} &= 125^\circ \mathrm{C} \\ \theta_{\mathsf{JA}} &= 93^\circ \mathrm{C/W} \text{ (for the DFN package)} \end{array}$

Substituting 0.25W for $P_{D(MAX)}$ and solving for the ambient operating temperature will give the maximum operating conditions for the regulator circuit. The maximum power dissipation must not be exceeded for proper operation.

EQUATION 4-5:

$$0.25W = \frac{125^{\circ}C - T_A}{93^{\circ}C/W}$$
$$T_A = 101.75^{\circ}C$$

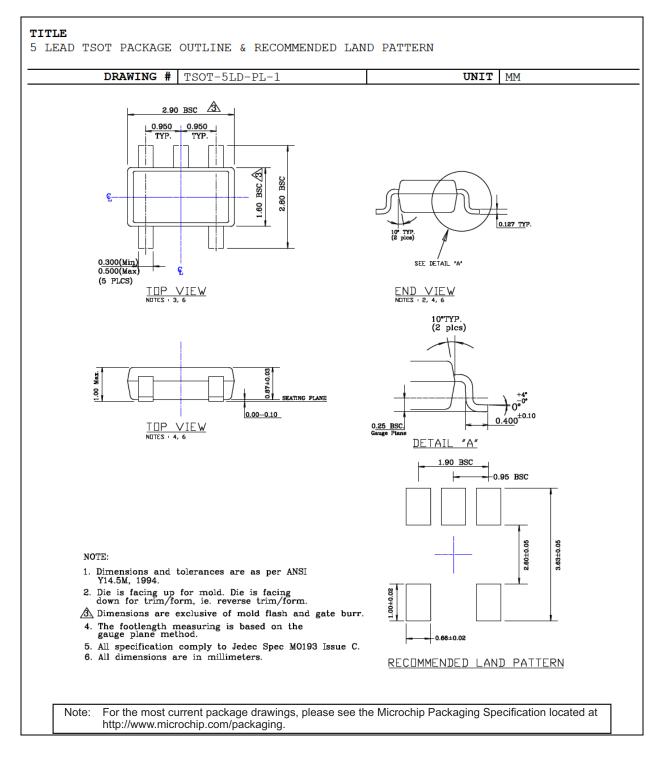
Therefore, a 2.8V application at 500 mA of output current can accept an ambient operating temperature of 101.75°C in a 2 mm x 2 mm DFN package. For a full discussion of heat sinking and thermal effects on voltage regulators, refer to the "Regulator Thermals" section of Microchip's Designing with Low-Dropout Voltage Regulators handbook.

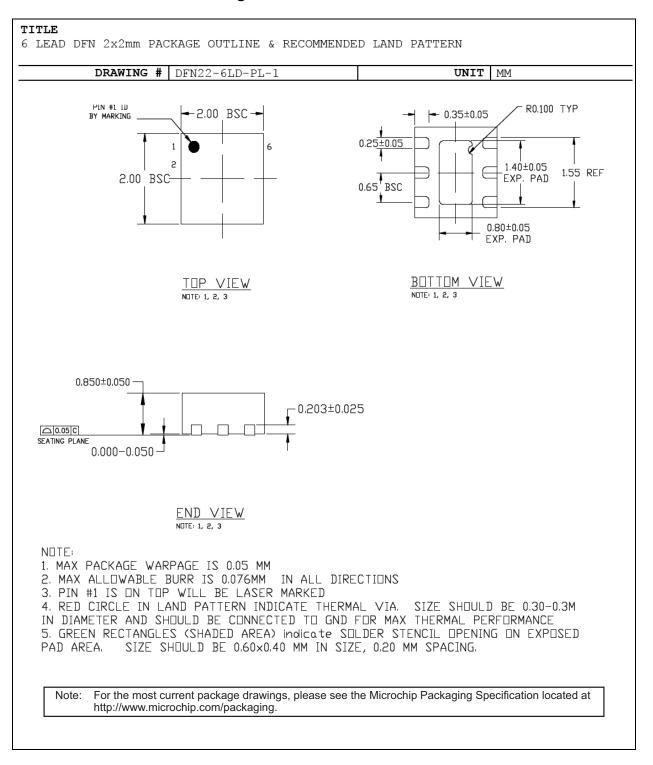
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

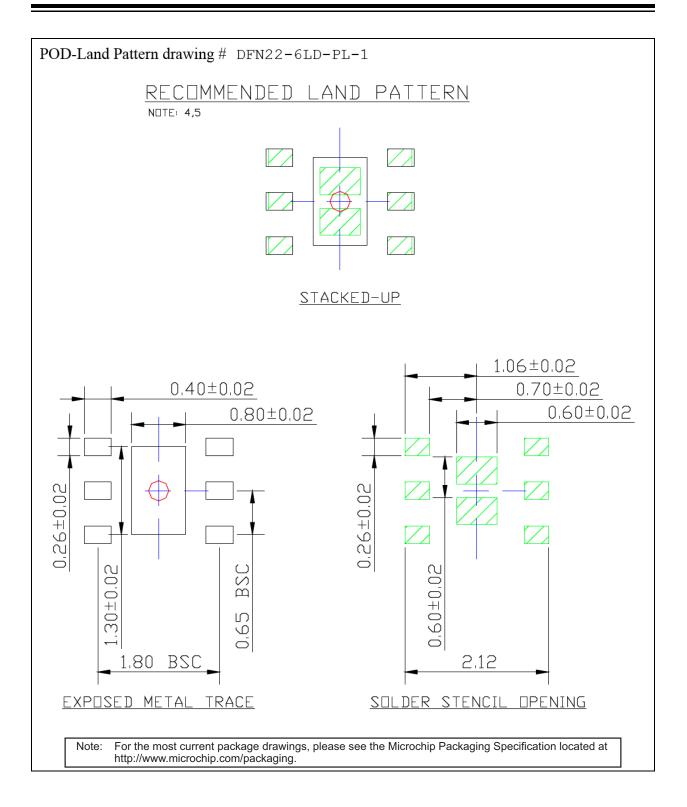
		Part Number	Marking	
<u>XX</u> XX		MIC5319YML-TR	9ĀA	<u>Z3</u> 1J
NNN		MIC5319-5.0YML-TR	950	689
		MIC5319-5.0YD5-TR	<u>N9</u> 50	
		MIC5319-3.3YML-TR	933	
		MIC5319-3.3YD5-TR	<u>N9</u> 33	
		MIC5319-3.0YML-TR	930	
		MIC5319-3.0YD5-TR	<u>N9</u> 30	
6-Pin DF	-N*	MIC5319-2.9YML-TR	<u>N9</u> 29	Example
		MIC5319-2.8YML-TR	928	
XXX		MIC5319-2.8YD5-TR	<u>N9</u> 28	▲ 933
		MIC5319-2.85YML-TR	<u>92</u> J	
NNN		MIC5319-2.7YML-TR	927	689
		MIC5319-2.7YD5-TR	<u>N9</u> 27	
		MIC5319-2.6YML-TR	926	
		MIC5319-2.6YD5-TX	<u>N9</u> 26	
		MIC5319-2.6YD5-TR	<u>N9</u> 26	
		MIC5319-2.5YML-TR	925	
		MIC5319-2.5YD5-TX	<u>N9</u> 25	
		MIC5319-2.5YD5-TR	<u>N9</u> 25	
		MIC5319-1.8YML-TR	918	
		MIC5319-1.8YD5-TX	<u>N9</u> 18	
		MIC5319-1.8YD5-TR	<u>N9</u> 18	
		MIC5319-1.85YML-TR	91J	
		MIC5319-1.85YD5-TX	<u>N9</u> 1J	
		MIC5319-1.85YD5-TR	<u>N9</u> 1J	
		MIC5319-1.3HYML-TR	<u>13</u> H	
		MIC5319-1.3HYD5-TR	<u>N1</u> 3H	
-	Y Y YY Y WW V NNN A @3 F * T	Product code or customer- ear code (last digit of cale ear code (last 2 digits of c Veek code (week of Janua Iphanumeric traceability c b-free JEDEC [®] designato his package is Pb-free. Th an be found on the outer	ndar year) alendar year) ary 1 is week 'C ode or for Matte Tin he Pb-free JEE	01') I (Sn) DEC designator ()
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		and/or Overbar (⁻) symbo		







6-Lead DFN 2 mm x 2 mm Package Outline and Recommended Land Pattern



APPENDIX A: REVISION HISTORY

Revision A (October 2017)

- Converted Micrel document MIC5319 to Microchip data sheet DS20005876A.
- Minor text changes throughout.

Revision B (February 2018)

• Replaced the incorrect DFN 2x2 package drawing with the correct version.

MIC5319

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

<u>PART NO.</u>	<u>-X.X X XX -XX</u>	Examples:
Device	Output Voltage Junction Temp. Package Media Type MIC5319: 500 mA µCap Ultra-Low Dropout High PSRR LDO Regulator	a) MIC5319-1.3HYML-TR: 500 mA µCap Ultra-Low Dropout High PSRR LDO Regulator, 1.375V Output Voltage, -40°C to +125°C, 6-Lead DFN, 5,000/Reel
Voltage:	<pre> <br <="" td=""/><td>b) MIC5319YD5-TX: 500 mA µCap Ultra-Low Dropout High PSRR LDO Regulator, Adjustable Output Voltage, -40°C to +125°C, 5-Lead TSOT23, 3,000/Reel w/ Reversed Pin 1</td></pre>	b) MIC5319YD5-TX: 500 mA µCap Ultra-Low Dropout High PSRR LDO Regulator, Adjustable Output Voltage, -40°C to +125°C, 5-Lead TSOT23, 3,000/Reel w/ Reversed Pin 1
	2.8 = 2.8V 2.85 = 2.8V (DFN Only) 2.9 = 2.9V (DFN Only) 3.0 = 3.0V 3.3 = 3.3V 5.0 = 5.0V	c) MIC5319-2.7YML-TR: 500 mA µCap Ultra-Low Dropout High PSRR LDO Regulator, 2.7V Output Voltage, -40°C to +125°C, 6-Lead DFN, 5,000/Reel
Junction Temperature Range:	Y = -40°C to +125°C RoHS-Compliant	d) MIC5319-3.0YD5-TR: 500 mA µCap Ultra-Low Dropout High PSRR LDO Regulator, 3.0V Output Voltage, -40°C to +125°C, 5-Lead TSOT23, 3,000/ Reel
Package: Media Type:	D5 = 5-Lead TSOT23 ML = 6-Lead 2 mm x 2 mm DFN TX = 3,000/Reel (with reversed Pin 1; D5 only) TR = 3,000/Reel (D5) TR = 5,000/Reel (ML)	e) MIC5319-2.85YML-TR: 500 mA µCap Ultra-Low Dropout High PSRR LDO Regulator, 2.85V Output Voltage, -40°C to +125°C, 6-Lead DFN, 5,000/Reel
	TK - 5,000/Reg (ML)	f) MIC5319-5.0YD5-TX: 500 mA µCap Ultra-Low Dropout High PSRR LDO Regulator, 5.0V Output Voltage, -40°C to +125°C, 5-Lead TSOT23, 3,000/ Reel w/ Reversed Pin 1
		Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

MIC5319

NOTES:

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